

2.7W Mono Fully Differential Audio Power Amplifier

General Description

The EMA2004 is a 2.7W mono fully differential amplifier designed to drive a speaker with at least 4Ω impedance while consuming only $20~\text{mm}^2$ total PCB area in most applications. The device operates from 2.5 V to 5.5 V, drawing only 5mA of quiescent supply current. The EMA2004 is available in the space-saving 3 mm x 3 mm TDFN package.

The EMA2004 is ideal for PDA/smart phone applications due to features such as -70dB supply voltage rejection from 20 Hz to 2 kHz, improved RF rectification immunity, small PCB area, and a fast startup with minimal pop.

Features

- · Designed for Wireless or Cellular Handsets and PDAs
- \cdot 2.7 W Into 4 Ω From a 5-V Supply at THD = 10% (Typ)
- · Low Supply Current: 5mA (Typ) at 5 V
- · Shutdown Current: 0.1 µA (Typ)
- · Fast Startup With Minimal Pop
- · Only Three External Components
- · Improved PSRR (-70 dB) and Wide Supply Voltage (2.5 V to 5.5 V) for Direct Battery Operation
- · Fully Differential Design Reduces RF Rectification
- ·-63 dB CMRR Eliminates Two Input Coupling Capacitors
- · Pin to Pin Compatible With TPA6204A1 in TDFN Package
- · Available in 3 mm X 3 mm TDFN Package

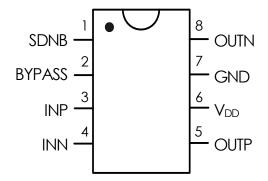
Applications

- · Ideal for Wireless Handsets
- · PDAs
- · Notebook Computers

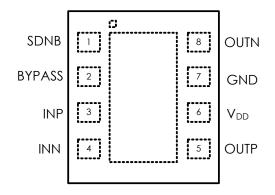


Connection Diagram

MSOP Package



TDFN Package



Order information

EMA2004-50MA08GRR/NRR

50 5.0V Operation
MA08 MSOP-8 Package
GRR RoHS (Pb Free)
Rating: -40 to 85°C
Package in Tape & Reel

NRR RoHS & Halogen free (By Request)

Rating: -40 to 85°C Package in Tape & Reel

EMA2004-50FF08NRR

50 5.0V Operation
FF08 TDFN-8 Package
NRR RoHS & Halogen free
Rating: -40 to 85°C
Package in Tape & Reel

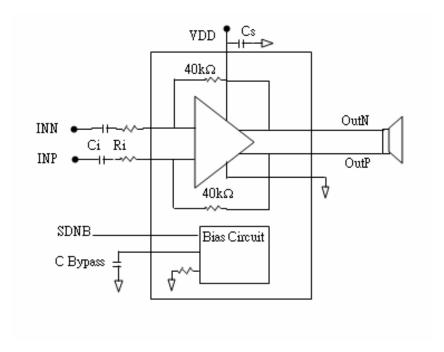
Order, Mark & Packing Information

Package	Product ID	Marking	Packing
MSOP-8	EMA2004-50MA08GRR	OA STANDOT SHAPE AND A STANDON	3K units Tape & Reel
TDFN-8	EMA2004-50FF08NRR	EMAZO04 Tracking Code	5K units Tape & Reel

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Typical Application



 $\begin{array}{c} {\rm R_{I}{=}40k\,\Omega\,,} \\ {\rm C_{I}{=}0.39\,\mu\,F,} \\ {\rm C_{S}{=}1\,\mu\,F} \\ {\rm C_{(BYPASS)}{=}0.22\,\mu\,F} \end{array}$

FIGURE 1. Typical Audio Amplifier Application Circuit with differential input

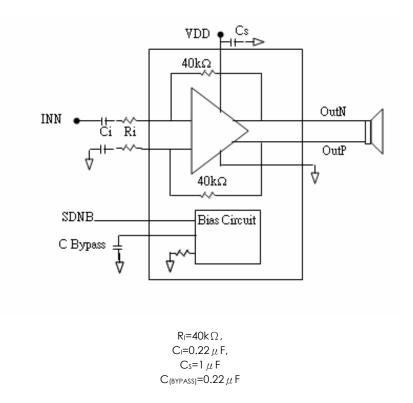


FIGURE 2. Typical Audio Amplifier Application Circuit with single-ended input



Absolute Maximum Ratings

Supply Voltage Storage Temperature Input Voltage Power Dissipation ESD Susceptibility

Junction Temperature

6.0V -65°C to +150°C -0.3V to VDD +0.3V Internally Limited HBM 1.5KV MM 200V 150°C Thermal Resistance

\$\theta_{JA}\$ (MSOP)

\$\theta_{JA}\$ (TDFN)

Operating Ratings

Temperature Range

Supply Voltage

190°C/W 160°C/W

 $-40^{\circ}\text{C} \le \text{TA} \le 85^{\circ}\text{C}$ $2.2\text{V} \le \text{VDD} \le 5.5\text{V}$

Electrical Characteristics V_{DD} = 5V

The following specifications apply for V_{DD} = 5V , A_V = 1 and R_L =8 Ω unless otherwise specified. Limits apply for T_A = 25°C.

			Conditions			
Symbol	Parameter	Conditions	Typical	Limit	Units	
lob	Quiescent Power Supply Current	uiescent Power Supply Current $V_{IN} = 0V$, $IO = 0A$		8	mA	
I _{SD}	Shutdown Current	V _{SDNB} =GND	0.1	1	μA	
Vos	Output offset voltage V_{I} =0V differential, A_{V} =1 V/V, V_{DD} = 5.5 V		1	5	mV	
Ро	Po Output Power	THD+N = 10 %(max), f = 1kHz $R_L = 4\Omega$ $R_L = 8\Omega$	2.7 1.7		W	
		THD+N = 1%(max), f = 1kHz $R_L = 4\Omega$ $R_L = 8\Omega$	2.1 1.4			
THD+N	Total Harmonic Distortion + Noise	VDD = 3.6V, RL=8 Ω , f = 1kHz Po = 0.6 Wrms Po= 0.25 Wrms Po = 0.1 Wrms	0.007 0.01 0.017		%	
PSRR	Power Supply Rejection Ratio	V _{ripple} =200mV sine p-p, input ac-grounded			dB	
		f=217Hz	-70			
		f=20 to 20kHz	-65			
CMRR	Common Mode Rejection Ratio	$V_{DD} = 3.6V$, $V_{IC} = 1V_{PP}$, $f = 217Hz$	60		dB	

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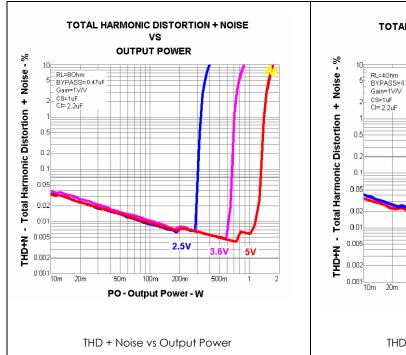


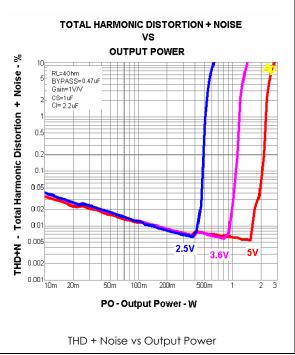
Electrical Characteristics $V_{DD} = 2.5V$ The following specifications apply for $V_{DD} = 2.5V$, $A_V = 1$ and $R_L = 8\Omega$ unless otherwise specified. Limits apply for $T_A = 25^{\circ}C$.

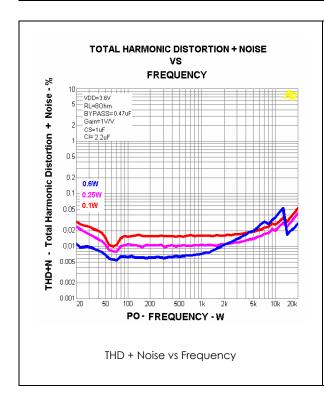
3 4 4 4	. , ,		Conditions		Units	
Symbol Parameter		Conditions	Typical	Limit		
I _{DD}	Quiescent Power Supply Current	V _{IN} = 0V, Io = 0A	4	8	mA	
I _{SD}	Shutdown Current	V _{SDNB} =GND	0.1	1	μΑ	
Po	Output Power	THD+N = 10 %(max), f = 1kH $R_L = 4\Omega \\ R_L = 8\Omega$ ower			w	
		$THD+N=1\%(max),f=1kHz$ $R_L=4\Omega$ $R_L=8\Omega$	0.5 0.3			
PSRR	Power Supply Rejection Ratio	V _{ripple} =200mV sine p-p, input ac-grounded				
		f=217Hz	-70		dB	
		f=20 to 20kHz	-65			

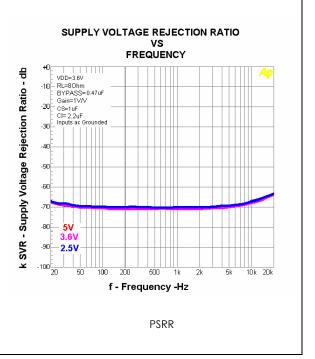


Typical Performance Characteristics

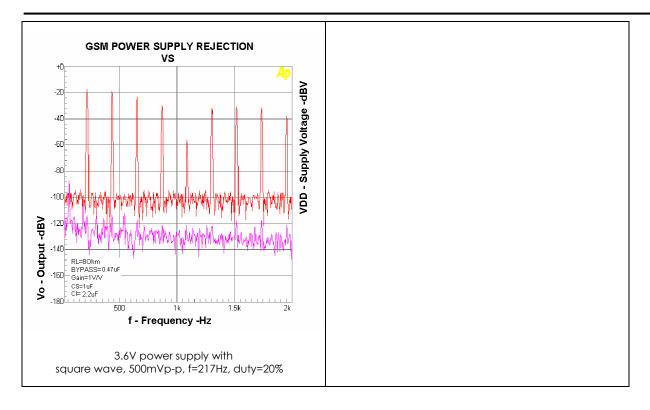






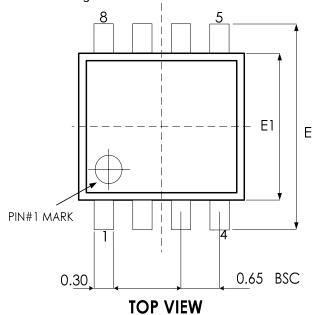


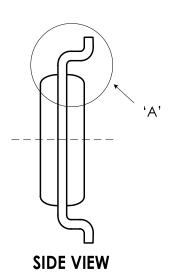


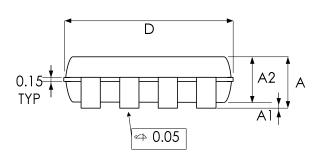


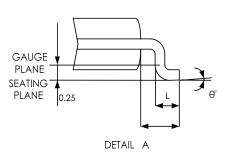


Physical Dimensions MSOP-8 Plastic Package









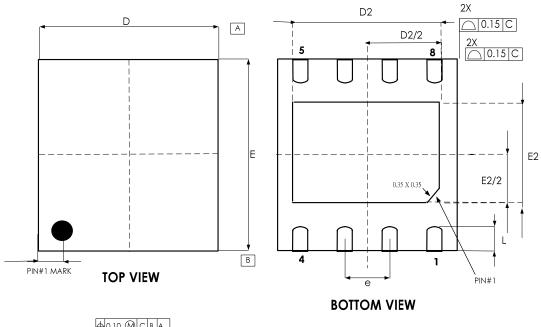
BOTTOM VIEW

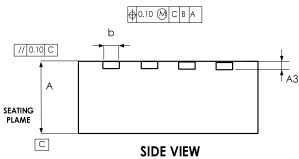
SYMBOLS	MIN.	NOM.	MAX.		
А	-	-	1.10		
A1	0.00	0.00 - 0.15			
A2	0.75	0.85	0.95		
D		3.00 BSC			
Е	4.90 BSC				
E1		3.00 BSC			
L	0.40 0.60 0.80		0.80		
L1		0.95 REF			
$ heta$ $^{\circ}$	0	-	8		

UNIT: MM



TDFN-8





	COMMON					
SYMBOL	DIMENSIONS MILLIMETER			DIMENSIONS INCH		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.70	0.75	0.80	0.028	0.030	0.031
A3	0.203 BSC			0.008 BSC		
b	0.25	0.30	0.35	0.010	0.012	0.014
D	3.00 BSC			0.118BSC		
D2	1.60	-	2.50	0.063	-	0.098
Е	3.00 BSC				0.118BSC	
E2	1.35	-	1.75	0.053	-	0.069
е	0.650 BSC				0.026 BSC	
L	0.30	0.40	0.50	0.012	0.016	0.020



Revision History

Revision	Date	Description
4.0	2009.07.15	EMP transferred from version 3.1
4.1	2010.10.07	Package dimension update



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